

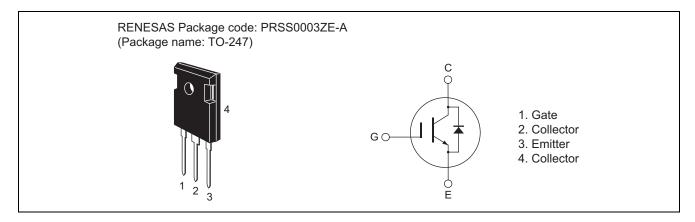
RJH60D5BDPQ-E0

600V - 37A - IGBT Application: Inverter R07DS0794EJ0300 Rev.3.00 May 23, 2013

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 \text{ V}$ typ. (at $I_C = 37 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=50 \text{ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=37$ A, $Rg=5$ Ω, $Ta=25^{\circ}$C, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	75	Α
	Tc = 100°C	Ic	37	Α
Collector peak current		ic(peak) Note1	150	Α
Collector to emitter diode forward current		I _{DF}	30	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	120	Α
Collector dissipation		P _C Note2	200	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.63	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	1.1	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

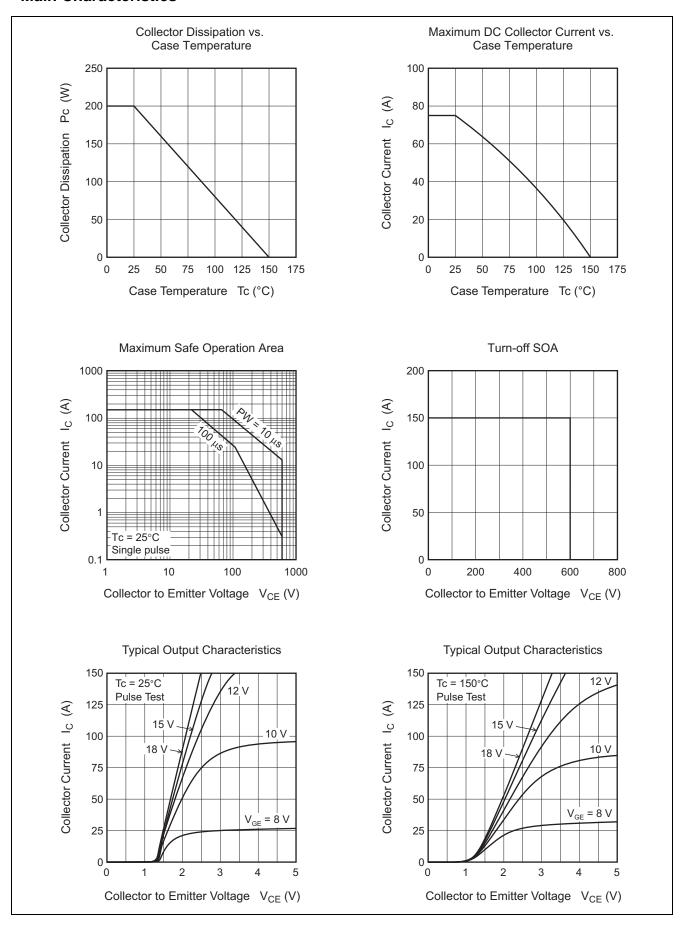
 $(Ta = 25^{\circ}C)$

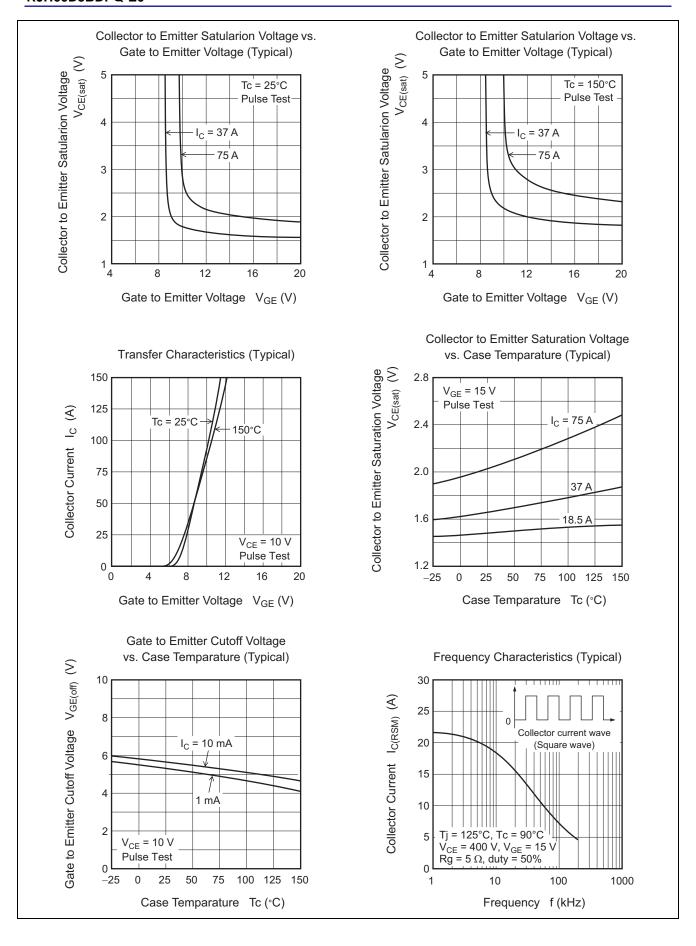
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_C = 37 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.0	_	V	$I_C = 75 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1900	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	120	_	pF	$V_{GE} = 0$	
Reveres transfer capacitance	Cres	_	60	_	pF	f = 1 MHz	
Total gate charge	Qg	_	78	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	12	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	36	_	nC	I _C = 37 A	
Turn-on delay time	t _{d(on)}	_	50	_	ns	V _{CC} = 300 V	
Rise time	t _r	_	40	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	130	_	ns	I _C = 37 A	
Fall time	t _f	_	50	_	ns	$Rg = 5 \Omega$	
Turn-on energy	Eon	_	0.40	_	mJ	Inductive load	
Turn-off energy	E _{off}	_	0.81	_	mJ		
Total switching energy	E _{total}	_	1.21	_	mJ		
Short circuit withstand time	t _{sc}	3.0	5.0	_	μs	$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$	
FRD Forward voltage	V _F	_	2.5	3.0	V	I _F = 30 A ^{Note3}	
EDD roverse recovery time	+		25	1	no	I - 20 A	

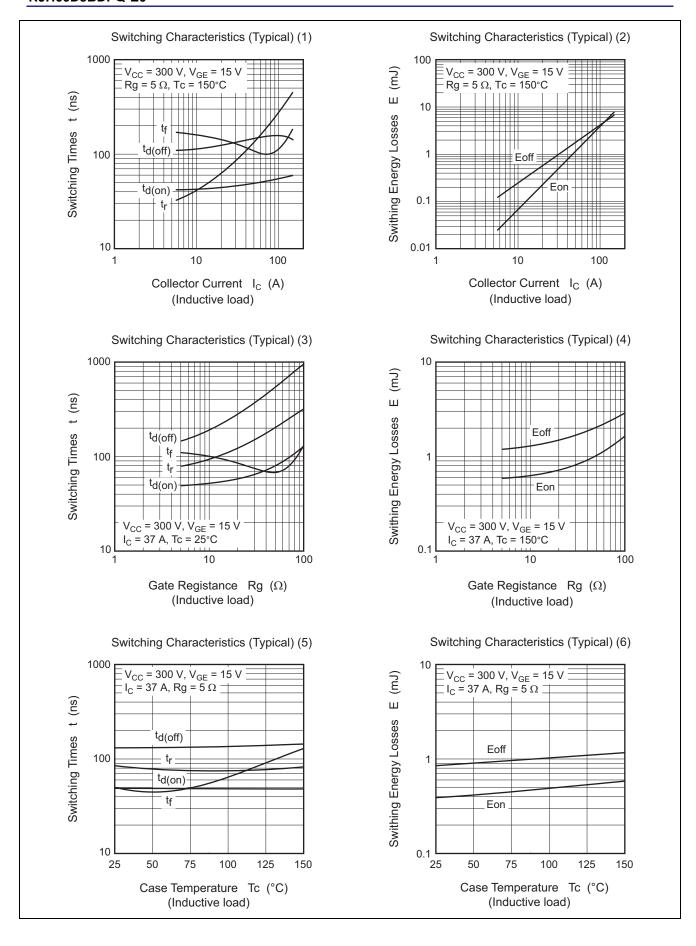
FRD Forward voltage	V_{F}	_	2.5	3.0	V	$I_F = 30 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	25	_	ns	I _F = 30 A
FRD reverse recovery charge	Q _{rr}	_	26	_	nC	$di_F/dt = 100 A/\mu s$
FRD peak reverse recovery current	I _{rr}	_	1.3	_	Α	

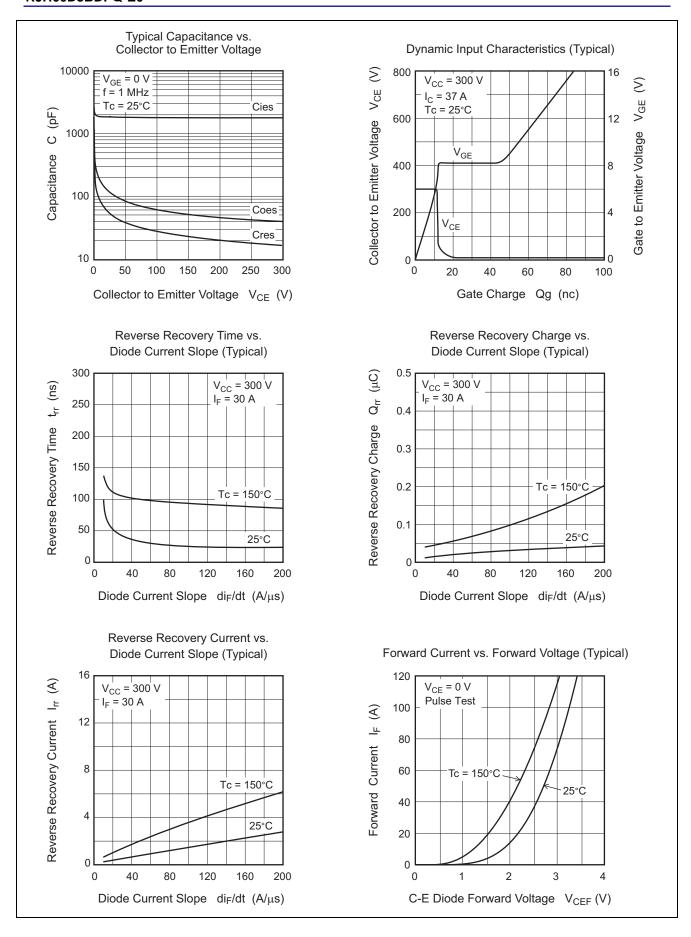
Notes: 3. Pulse test.

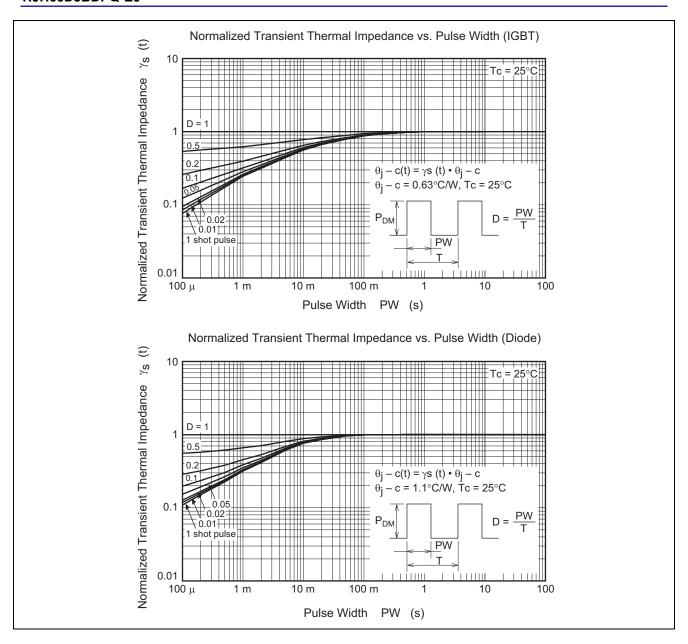
Main Characteristics

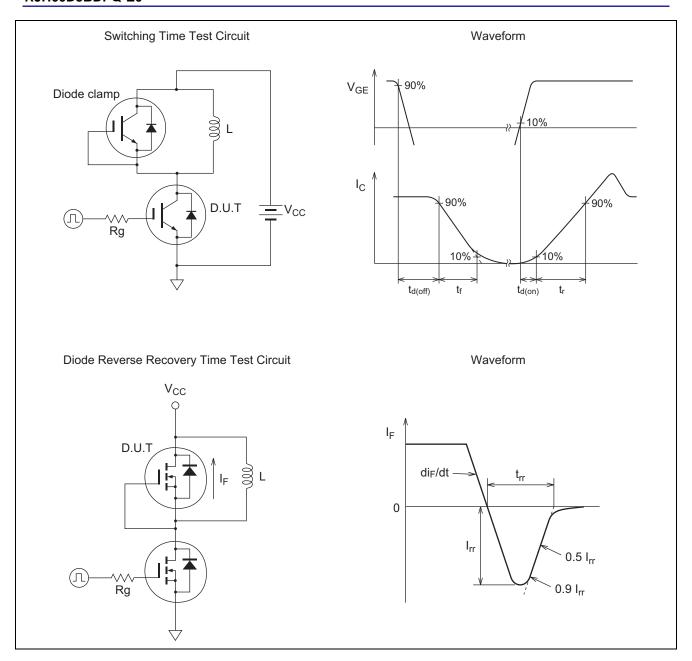




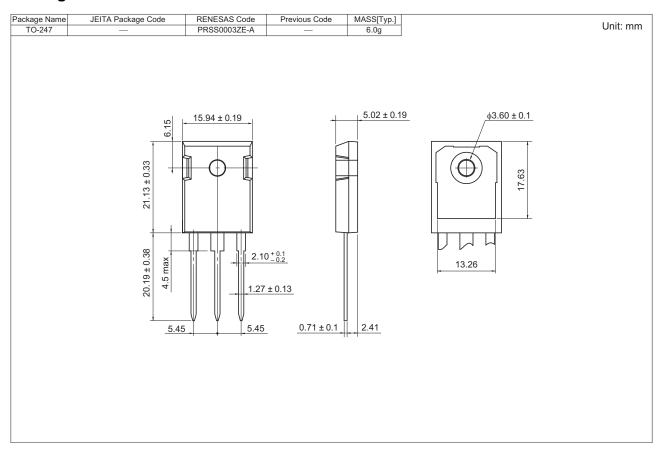








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D5BDPQ-E0#T2	240 pcs	Box (Tube)

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